

## W-Band Power Amplifier, 75 to 110 GHz, 20 dB Gain, +30 dBm P<sub>sat</sub>

**SBP-7531142030-1010-EP** is a W-band GaN power amplifier with a typical small signal gain of 20 dB and a typical  $P_{sat}$  of +30 dBm across the frequency range of 75 to 110 GHz. The DC power requirement for the amplifier is +15  $V_{DC}/1.6$  A. The mechanical configurations is an inline structure with WR-10 waveguides and UG-387/U-M anti-cocking flanges. Power amplifier module comes with heatsink and fan asssembled with the unit.



## **Electrical Specifications:**

Parameter	Minimum	Typical	Maximum	
Frequency	75 GHz		110 GHz	
Small Signal Gain		20 dB		
Power Gain		10 dB		
P <sub>sat</sub>		+30 dBm		
Pin			+30 dBm	
Input Return Loss		7 dB		
Output Return Loss without Damage		5 dB		
DC Supply Voltage (VDD)	+14 V <sub>DC</sub>	+15 V <sub>DC</sub>	+20 V <sub>DC</sub>	
DC Supply Current		1.6 A		
Supply Voltage to Fan		+12 V <sub>DC</sub> /0.6 A		
Specification Temperature		+25 °C		
Operating Temperature	0°C		+50 °C	

## **Mechanical Specifications:**

Item	Specification
Input	WR-10 Waveguide with UG-387/U-M Anti-Coking Flange
Output	WR-10 Waveguide with UG-387/U-M Anti-Coking Flange
Power Supply	Solder Pin
Case Material	Aluminum
Finish	Gold Plated
Size	3.15" (L) X 2.99" (W) X 3.69" (H)
Outline	BP-HW-H1

#### **ECCN**

3A001.b.4

## **FEATURES**

- Class AB GaN Technique
- Broadband Performance
- · High Gain
- · High Output Power
- Forced Air Cooling
- In-line Port Configuration

#### **APPLICATIONS**

- Radar Systems
- Communication Systems
- Test Equipment

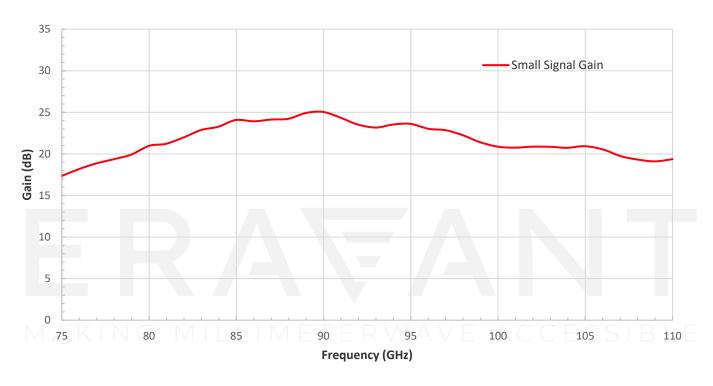
### **SUPPLEMENTAL DETAILS**



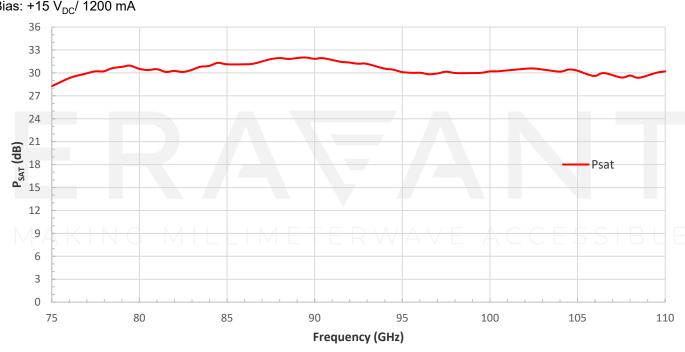




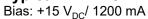
## Typical Gain vs. Frequency

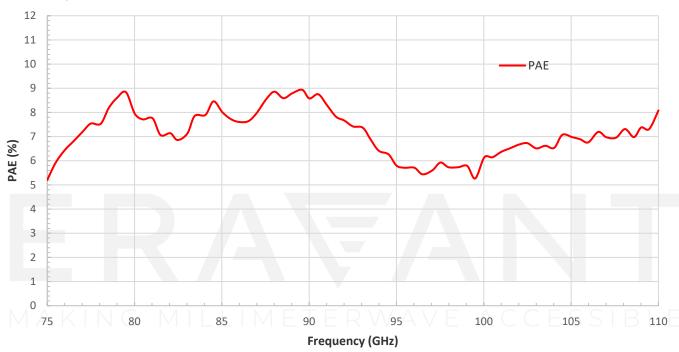


# Typical $P_{SAT}$ vs. Frequency Bias: +15 $V_{DC}/$ 1200 mA

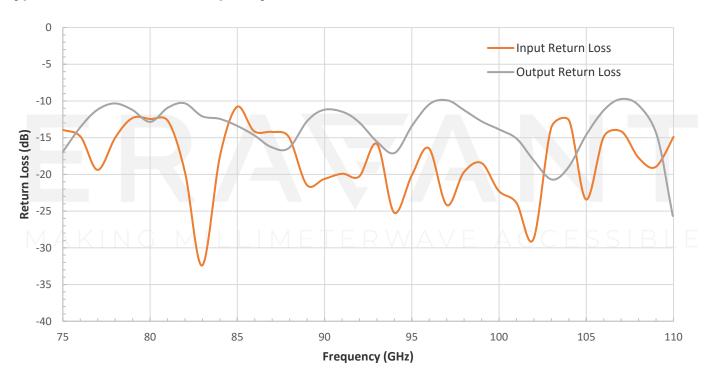


## Typical PAE vs. Frequency



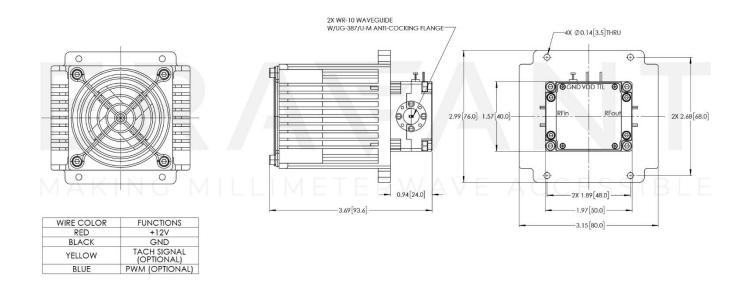


## Typical Return Loss vs. Frequency





## Mechanical Outline: (Unless otherwise specified, all dimensions are in inches [millimeters])



#### NOTE:

- All data presented is collected from a sample lot. Actual data may vary unit to unit.
- All testing was performed under +25 °C case temperature.
- Other mechanical configurations are available under different model numbers.
- Eravant reserves the right to change the information presented without notice.

#### **CAUTION:**

- Exceeding absolute maximum ratings shown will damage the device.
- Do not block the air inlets and outlets.
- The device is static sensitive. Always follow ESD rules when working with the device.
- Do not plug or unplug any connectors when amplifier is activated. All connectors must be connected/disconnected when amplifier is off.
- The case temperature of the device shall never exceed +50 °C. Use proper heatsink or fan if necessary
- Any foreign objects in the waveguide will degrade performance and/or damage the device.

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